

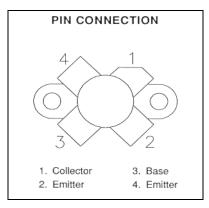
RF & MICROWAVE TRANSISTORS HF SSB APPLICATIONS

Features

30 MHz 50 VOLTS $P_{OUT} = 150$ WATTS $G_P = 14$ dB MINIMUM COMMON EMITTER CONFIGURATION

DESCRIPTION:

The MS1007 is a 50V epitaxial silicon NPN planar transistor designed primarily for SSB communications. This device utilizes emitter ballasting to achieve extreme ruggedness under severe operating conditions.

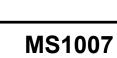


ABSOLUTE MAXIMUM RATINGS (Tcase = 25 C)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	110	V
V _{CEO}	Collector-Emitter Voltage	55	V
V _{EBO}	Emitter-Base Voltage	4.0	V
Ιc	Device Current	10	Α
P _{DISS}	Power Dissipation	233	W
TJ	Junction Temperature	+200	С
T _{STG}	Storage Temperature	-65 to +150	С

Thermal Data

R _{TH(J-C)} Thermal Resistance Junction-case	0.75	C/W
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MS1007

ELECTRICAL SPECIFICATIONS (Tcase = 25 \circ C) Static

Symbol		Test Conditions		Value			
			Min.	Тур.	Max.	Unit	
BV _{CBO}	l _c = 100mA	l _E = 0mA	110			V	
BV _{CES}	I _c = 100mA	V _{BE} = 0V	110			V	
BV _{CEO}	I _c = 100mA	I _в = 0mА	55			V	
BV _{EBO}	I _E = 10mA	I _c = 0mA	4.0			V	
I _{CEO}	V _{CE} = 30V	I _E = 0 mA			5	mA	
I _{CES}	V _{CE} = 60V	l _E = 0mA			5	mA	
h _{FE}	V _{CE} = 6V	I _C = 1.4A	18		43.5		

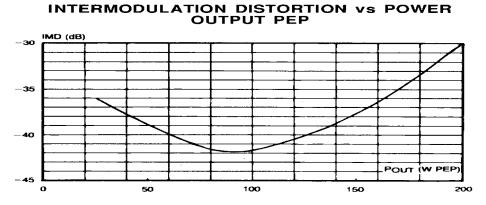
DYNAMIC

Symbol	Test Conditions			Value			
				Min.	Тур.	Max.	Unit
Pout	f = 30 MHz	V _{CE} = 50V	I _{CQ} = 100mA	150			WPEP
G₽	P _{OUT} = 150WPEP	V _{CE} = 50V	I _{CQ} = 100mA	14			dB
IMD	P _{OUT} = 150WPEP	V _{CE} = 50V	I _{CQ} = 100mA			-30	dBc
η _c	P _{OUT} = 150WPEP	V _{CE} = 50V	I _{CQ} = 100mA	37			%
С _{ов}	f = 1 MHz	V _{CB} = 50 V				220	pf
Conditions	f1 = 30.000MHz	f2 = 30.001N	IHz				

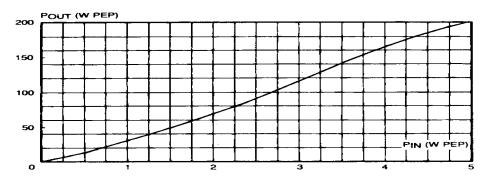


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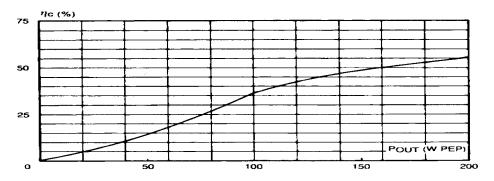
TYPICAL PERFORMANCE









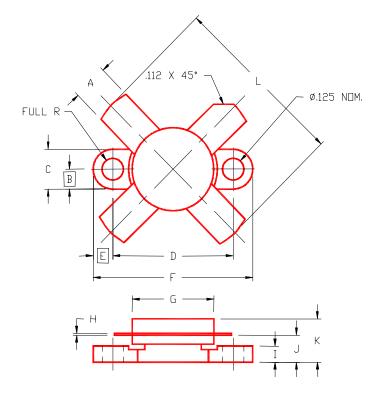




MS1007

PACKAGE MECHANICAL DATA





	MINIMUM	MAXIMUM			MINIMUM	MAXIMUM
	INCHES/MM	INCHES/MM			INCHES/MM	INCHES/MM
A	.220/5,59	.230/5,84		Ι	.090/2,29	.110/2,79
В	.125/3,18				.160/4,06	.175/4,45
С	.245/6,22	.255/6,48		К		.280/7,11
D	,720/18,28	.730/18,54		L		1.050/26,67
Ε	.125/3,18					
F	,970/24,64	.980/24,89				
G	,495/12,57	.505/12,83				
Н	.003/0,08	.007/0,18				